

# isc Silicon PNP Power Transistor

2SB1230

#### **DESCRIPTION**

- · Collector-Emitter Breakdown Voltage-
  - : V<sub>(BR)CEO</sub>= -100V(Min)
- · High Current Capability
- · Wide Area of Safe Operation
- Complement to Type 2SD1840
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

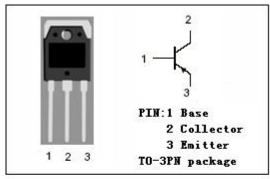
### **APPLICATIONS**

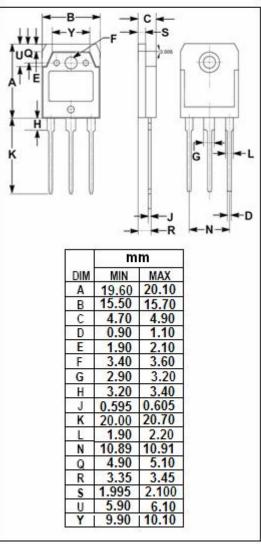
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• Designed for motor drivers, converters and other general High-current switching applications.

## ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>CBO</sub>	Collector-Base Voltage	-110	V	
V <sub>CEO</sub>	Collector-Emitter Voltage	-100	V	
V <sub>EBO</sub>	Emitter-Base Voltage	-6	V	
Ic	Collector Current-Continuous	-15	А	
I <sub>CP</sub>	Collector Current-Pulse	-25	Α	
l <sub>Β</sub>	Base Current-Continuous -5		А	
	Collector Power Dissipation @ T <sub>a</sub> =25°C	3	W	
Pc	Collector Power Dissipation @ T <sub>C</sub> =25°C	100		
TJ	Junction Temperature 150		$^{\circ}$	
T <sub>stg</sub>	Storage Temperature Range -55~150		$^{\circ}$	







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#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = -5mA ; R <sub>BE</sub> =∞	-100			V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> = -1mA; I <sub>E</sub> = 0	-110			V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = -1mA; I <sub>C</sub> = 0	-6			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = -6A; I <sub>B</sub> = -0.6A			-0.8	V
V <sub>BE(sat)</sub>	Base -Emitter Saturation Voltage	I <sub>C</sub> = -6A; I <sub>B</sub> = -0.6A			-1.5	V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = -100V; I <sub>E</sub> = 0			-100	μА
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = -5V; I <sub>C</sub> = 0			-100	μА
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = -1.5A; V <sub>CE</sub> = -2V	50		140	
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = -6A; V <sub>CE</sub> = -2V	20			

## h<sub>FE-1</sub> Classifications

Р	Q		
50-100	70-140		

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